

REVISIONS																			
LTR	DESCRIPTION												DATE (YR-MO-DA)				APPROVED		
A	Drawing updated to reflect current requirements. -ro												01-03-21				R. MONNIN		
B	Five year review requirement. -rrp												08-02-25				R. HEBER		
REV																			
SHEET																			
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REV STATUS					REV		B	B	B	B	B	B	B	B	B				
OF SHEETS					SHEET		1	2	3	4	5	6	7	8	9				
PMIC N/A					PREPARED BY RICK C. OFFICER					DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43218-3990 http://www.dscc.dla.mil									
STANDARD MICROCIRCUIT DRAWING THIS DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE AMSC N/A					CHECKED BY CHARLES E. BESORE														
					APPROVED BY MICHAEL A. FRYE														
					DRAWING APPROVAL DATE 93-01-11					MICROCIRCUIT, LINEAR, HIGH SPEED, OPERATIONAL AMPLIFIER, MONOLITHIC SILICON									
					REVISION LEVEL B														
					SIZE A		CAGE CODE 67268			5962-89646									
					SHEET 1 OF 9														

1. SCOPE

1.1 Scope. This drawing describes device requirements for MIL-STD-883 compliant, non-JAN class level B microcircuits in accordance with MIL-PRF-38535, appendix A.

1.2 Part or Identifying Number (PIN). The complete PIN is as shown in the following example:

<u>5962-89646</u>	<u>01</u>	<u>P</u>	<u>X</u>
Drawing number	Device type (see 1.2.1)	Case outline (see 1.2.2)	Lead finish (see 1.2.3)

1.2.1 Device type(s). The device type(s) identify the circuit function as follows:

<u>Device type</u>	<u>Generic number</u>	<u>Circuit function</u>
01	AD846	High speed operational amplifier

1.2.2 Case outline(s). The case outline(s) are as designated in MIL-STD-1835 and as follows:

<u>Outline letter</u>	<u>Descriptive designator</u>	<u>Terminals</u>	<u>Package style</u>
P	GDIP1-T8 or CDIP2-T8	8	Dual-in-line

1.2.3 Lead finish. The lead finish is as specified in MIL-PRF-38535, appendix A.

1.3 Absolute maximum ratings. 1/

Supply voltage (V_S)	± 18 V
Common mode input voltage	$ V_S - 3$ V
Output short circuit duration	Indefinite
Differential input voltage	± 1 V
Continuous input current:		
Inverting or noninverting	2.0 mA
Internal power dissipation (P_D):		
Cavity package	1.3 W <u>2/</u>
Lead temperature (soldering, 60 seconds)	+300°C
Storage temperature range	-65°C to +150°C
Thermal resistance, junction-to-case (θ_{JC})	+30°C/W
Thermal resistance, junction-to-ambient (θ_{JA})	+110°C/W

1.4 Recommended operating conditions.

Positive supply voltage ($+V_S$)	+15 V
Negative supply voltage ($-V_S$)	-15 V
Ambient operating temperature range (T_A)	-55°C to +125°C

1/ Stresses above the absolute maximum rating may cause permanent damage to the device. Extended operation at the maximum levels may degrade performance and affect reliability.

2/ Maximum internal power dissipation is specified so that T_J does not exceed +175°C at an ambient temperature of +25°C, derate P package at 8.7 mW/°C.

STANDARD MICROCIRCUIT DRAWING DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43218-3990	SIZE A		5962-89646
		REVISION LEVEL B	SHEET 2

2. APPLICABLE DOCUMENTS

2.1 Government specification, standards, and handbooks. The following specification, standards, and handbooks form a part of this drawing to the extent specified herein. Unless otherwise specified, the issues of these documents are those cited in the solicitation or contract.

DEPARTMENT OF DEFENSE SPECIFICATION

MIL-PRF-38535 - Integrated Circuits, Manufacturing, General Specification for.

DEPARTMENT OF DEFENSE STANDARDS

MIL-STD-883 - Test Method Standard Microcircuits.

MIL-STD-1835 - Interface Standard Electronic Component Case Outlines.

DEPARTMENT OF DEFENSE HANDBOOKS

MIL-HDBK-103 - List of Standard Microcircuit Drawings.

MIL-HDBK-780 - Standard Microcircuit Drawings.

(Copies of these documents are available online at <http://assist.daps.dla.mil/quicksearch/> or <http://assist.daps.dla.mil> or from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.)

2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

3. REQUIREMENTS

3.1 Item requirements. The individual item requirements shall be in accordance with MIL-PRF-38535, appendix A for non-JAN class level B devices and as specified herein. Product built to this drawing that is produced by a Qualified Manufacturer Listing (QML) certified and qualified manufacturer or a manufacturer who has been granted transitional certification to MIL-PRF-38535 may be processed as QML product in accordance with the manufacturers approved program plan and qualifying activity approval in accordance with MIL-PRF-38535. This QML flow as documented in the Quality Management (QM) plan may make modifications to the requirements herein. These modifications shall not affect form, fit, or function of the device. These modifications shall not affect the PIN as described herein. A "Q" or "QML" certification mark in accordance with MIL-PRF-38535 is required to identify when the QML flow option is used.

3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535, appendix A and herein.

3.2.1 Case outline. The case outline shall be in accordance with 1.2.2 herein.

3.2.2 Terminal connections. The terminal connections shall be as specified on figure 1.

3.3 Electrical performance characteristics. Unless otherwise specified herein, the electrical performance characteristics are as specified in table I and shall apply over the full ambient operating temperature range.

3.4 Electrical test requirements. The electrical test requirements shall be the subgroups specified in table II. The electrical tests for each subgroup are described in table I.

3.5 Marking. Marking shall be in accordance with MIL-PRF-38535, appendix A. The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked. For packages where marking of the entire SMD PIN number is not feasible due to space limitations, the manufacturer has the option of not marking the "5962-" on the device.

3.5.1 Certification/compliance mark. A compliance indicator "C" shall be marked on all non-JAN devices built in compliance to MIL-PRF-38535, appendix A. The compliance indicator "C" shall be replaced with a "Q" or "QML" certification mark in accordance with MIL-PRF-38535 to identify when the QML flow option is used.

STANDARD MICROCIRCUIT DRAWING DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43218-3990	SIZE A		5962-89646
		REVISION LEVEL B	SHEET 3

TABLE I. Electrical performance characteristics.

Test	Symbol	Conditions -55°C ≤ T _A ≤ +125°C V _S = ±15 V unless otherwise specified	Group A subgroups	Device type	Limits <u>1/</u>		Unit
					Min	Max	
Input offset voltage	V _{IO}	V _{CM} = 0 V <u>2/</u>	1	01	-200	+200	μV
			2,3		-350	+350	
Power supply rejection ratio	+PSRR	+V _S = +5 V to +18 V, -V _S = -15 V	1	01	110		dB
			2,3		94		
	-PSRR	+V _S = +15 V, -V _S = -5 V to -18 V	1		110		
			2,3		94		
Output voltage swing	+V _{OUT}	R _L = 500 Ω, T _A = +25°C	1	01	10		V
	-V _{OUT}					-10	
Quiescent current	I _Q	V _{OUT} = 0 V	1	01		6	mA
			2,3			7	
Input bias current	+I _{IB}	V _{CM} = 0 V <u>3/</u>	1	01	-15	+15	μA
			2,3		-20	+20	
	-I _{IB}		1		-450	+450	nA
			2,3		-1.5	+1.5	
Common mode input voltage range	+IVR	<u>4/</u>	1,2,3	01	+10		V
	-IVR					-10	
Open loop transresistance		V _{OUT} = ±10 V, R _L = 500 Ω	1	01	100		MΩ
			2,3		50		
Input bias current versus temperature	Δ+I _{IB} / ΔT	<u>3/</u> <u>5/</u>	4,5,6	01	-80	+80	nA/°C
	Δ-I _{IB} / ΔT				-20	+20	

See footnotes at end of table.

**STANDARD
MICROCIRCUIT DRAWING**
DEFENSE SUPPLY CENTER COLUMBUS
COLUMBUS, OHIO 43218-3990

SIZE
A

REVISION LEVEL
B

5962-89646

SHEET
4

TABLE I. Electrical performance characteristics – Continued.

Test	Symbol	Conditions $-55^{\circ}\text{C} \leq T_A \leq +125^{\circ}\text{C}$ $V_S = \pm 15\text{ V}$ unless otherwise specified	Group A subgroups	Device type	Limits <u>1/</u>		Unit
					Min	Max	
Input bias current versus supply	$\Delta I_{IB} /$ ΔV_S	$V_S = 5\text{ V to } +18\text{ V}$ <u>3/ 5/</u>	4	01	-15	+15	nA/V
			5,6		-20	+20	
	$\Delta I_{IB} /$ ΔV_S		4		-15	+15	
			5,6		-25	+25	
Input bias current versus common-mode	$\Delta I_{IB} /$ ΔV_{CM}	$V_{CM} = \pm 10\text{ V}$ <u>3/ 5/</u>	4	01	-15	+15	nA/V
			5,6		-20	+20	
	$\Delta I_{IB} /$ ΔV_{CM}		4		-10	+10	
			5,6		-20	+20	
Input resistance	$+R_{IN}$	$T_A = +25^{\circ}\text{C}$ <u>5/</u>	4	01	6		k Ω
	$-R_{IN}$				30		Ω
Common-mode rejection ratio	CMRR	$V_{CM} = \pm 10\text{ V}$	1	01	110		dB
			2,3		94		
Small signal bandwidth (-3 dB)	SSBW	$A_V = -1$, $R_F = 1\text{ k}\Omega$, <u>5/</u> $T_A = +25^{\circ}\text{C}$	4	01	50		MHz
Slew rate	+SR	$A_V = -1$, $R_L = 1\text{ k}\Omega$, <u>5/</u> $V_{OUT} = -5.0\text{ V to } 5.0\text{ V}$, measured from 10 percent to 90 percent point, rising edge	4	01	300		V/ μs
			5,6		200		
	-SR	$A_V = -1$, $R_L = 1\text{ k}\Omega$, <u>5/</u> $V_{OUT} = 5.0\text{ V to } -5.0\text{ V}$, measured from 90 percent to 10 percent point, falling edge	4		300		
			5,6		200		
Rise time	t_R	$A_V = -1$, $T_A = +25^{\circ}\text{C}$ <u>5/</u>	4	01		13	ns
Overshoot	OS	$A_V = -1$, $T_A = +25^{\circ}\text{C}$ <u>5/</u> $R_L = \infty$	4	01		35	%

See footnotes at end of table.

**STANDARD
MICROCIRCUIT DRAWING**
DEFENSE SUPPLY CENTER COLUMBUS
COLUMBUS, OHIO 43218-3990

SIZE
A

REVISION LEVEL
B

5962-89646

SHEET
5

TABLE I. Electrical performance characteristics – Continued.

Test	Symbol	Conditions -55°C ≤ T _A ≤ +125°C V _S = ±15 V unless otherwise specified	Group A subgroups	Device type	Limits <u>1/</u>		Unit
					Min	Max	
Settling time	t _S	A _V = -1, T _A = +25°C, <u>5/</u> 10 V step at 0.1 percent of the fixed value, R _L = ∞	4	01		120	ns

1/ The algebraic convention, whereby the most negative value is a minimum and the most positive is a maximum, is used in this table. Negative current shall be defined as conventional current flow of a device terminal.

2/ Input offset voltage parameters are guaranteed after the equivalent of 5 minutes at T_A = +25°C.

3/ Bias current parameters are guaranteed maximum after the equivalent of 5 minutes at T_A = +25°C.

4/ This parameter is guaranteed by testing common-mode rejection ratio.

5/ If not tested, this parameter shall be guaranteed to the limits specified in table I herein.

3.6 Certificate of compliance. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-HDBK-103 (see 6.6 herein). The certificate of compliance submitted to DSCC-VA prior to listing as an approved source of supply shall affirm that the manufacturer's product meets the requirements of MIL-PRF-38535, appendix A and the requirements herein.

3.7 Certificate of conformance. A certificate of conformance as required in MIL-PRF-38535, appendix A shall be provided with each lot of microcircuits delivered to this drawing.

3.8 Notification of change. Notification of change to DSCC-VA shall be required for any change that affects this drawing.

3.9 Verification and review. DSCC, DSCC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.

4. VERIFICATION

4.1 Sampling and inspection. Sampling and inspection procedures shall be in accordance with MIL-PRF-38535, appendix A.

4.2 Screening. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:

a. Burn-in test, method 1015 of MIL-STD-883.

(1) Test condition B. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015 of MIL-STD-883.

(2) T_A = +125°C, minimum.

b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.

STANDARD MICROCIRCUIT DRAWING DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43218-3990	SIZE A		5962-89646
		REVISION LEVEL B	SHEET 6

Device type	01
Case outline	P
Terminal number	Terminal symbol
1	NC
2	-INPUT
3	+INPUT
4	-V _S
5	COMPENSATION
6	OUTPUT
7	+V _S
8	NC

NC = No connection

FIGURE 1. Terminal connections.

STANDARD MICROCIRCUIT DRAWING DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43218-3990	SIZE A		5962-89646
		REVISION LEVEL B	SHEET 7

TABLE II. Electrical test requirements.

MIL-STD-883 test requirements	Subgroups (in accordance with MIL-STD-883, method 5005, table I)
Interim electrical parameters (method 5004)	1
Final electrical test parameters (method 5004)	1*,2,3,4,5,6
Group A test requirements (method 5005)	1,2,3,4,5,6
Groups C and D end-point electrical parameters (method 5005)	1

* PDA applies to subgroup 1.

4.3 Quality conformance inspection. Quality conformance inspection shall be in accordance with method 5005 of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.

4.3.1 Group A inspection.

- a. Tests shall be as specified in table II herein.
- b. Subgroups 7, 8, 9, 10, and 11 in table I, method 5005 of MIL-STD-883 shall be omitted.

4.3.2 Groups C and D inspections.

- a. End-point electrical parameters shall be as specified in table II herein.
- b. Steady-state life test conditions, method 1005 of MIL-STD-883.
 - (1) Test condition B. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1005 of MIL-STD-883.
 - (2) $T_A = +125^{\circ}\text{C}$, minimum.
 - (3) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-PRF-38535, appendix A.

STANDARD MICROCIRCUIT DRAWING DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43218-3990	SIZE A		5962-89646
		REVISION LEVEL B	SHEET 8

6. NOTES

6.1 Intended use. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.

6.2 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.

6.3 Configuration control of SMD's. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished using DD Form 1692, Engineering Change Proposal.

6.4 Record of users. Military and industrial users shall inform Defense Supply Center Columbus (DSCC) when a system application requires configuration control and the applicable SMD. DSCC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronics devices (FSC 5962) should contact DSCC-VA, telephone (614) 692-0544.

6.5 Comments. Comments on this drawing should be directed to DSCC-VA, Columbus, Ohio 43218-3990, or telephone (614) 692-0547

6.6 Approved sources of supply. Approved sources of supply are listed in MIL-HDBK-103. The vendors listed in MIL-HDBK-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DSCC-VA.

STANDARD MICROCIRCUIT DRAWING DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43218-3990	SIZE A		5962-89646
		REVISION LEVEL B	SHEET 9

STANDARD MICROCIRCUIT DRAWING BULLETIN

DATE: 08-02-25

Approved sources of supply for SMD 5962-89646 are listed below for immediate acquisition information only and shall be added to MIL-HDBK-103 and QML-38535 during the next revision. MIL-HDBK-103 and QML-38535 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DSCC-VA. This information bulletin is superseded by the next dated revision of MIL-HDBK-103 and QML-38535. DSCC maintains an online database of all current sources of supply at <http://www.dscclia.mil/Programs/Smcr/>.

Standard microcircuit drawing PIN <u>1</u> /	Vendor CAGE number	Vendor similar PIN <u>2</u> /
5962-8964601PA	<u>3</u> /	AD846SQ/883B

- 1/ The lead finish shown for each PIN representing a hermetic package is the most readily available from the manufacturer listed for that part. If the desired lead finish is not listed contact the vendor to determine its availability.
- 2/ Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.
- 3/ Not available from an approved source of supply. The last known supplier is listed below.

Vendor CAGE
number

24355

Vendor name
and address

Analog Devices
Route 1 Industrial Park
P.O. Box 9106
Norwood, MA 02062
Point of contact: 804 Woburn Street
Wilmington, MA 01887-3462

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